



Supporting Imformation

Hydrogen induced etching features of wrinkled graphene domains

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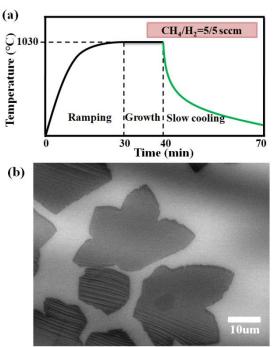


Figure S1. (a) Synthesis of graphene under slow cooling down process. (b) SEM images of as synthesized graphene domain.

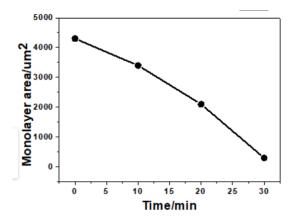


Figure S2. Statistical data of the area of monolayer graphene with etching time.